NSN 5961-01-130-8548

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View Online at https://aerobasegroup.com/nsn/5961-01-130-8548 **Inclosure Material:** Plastic **Overall Length:** Between 0.575 inches and 0.600 inches **Overall Height:** Between 0.160 inches and 0.190 inches Overall Width: Between 0.395 inches and 0.410 inches **End Application:** lp-1366 80009 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -140.0 collector to emitter voltage/static/base open and -140.0 collector to base voltage/static/emitter open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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